

1N4933 - 1N4937

FAST RECOVERY RECTIFIER DIODES

VOLTAGE RANGE: 50-600V CURRENT: 1.0 A

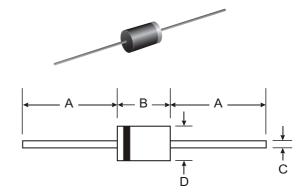
Features

- Diffused Junction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability

Mechanical Data

- Case: D O 4 1 Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.34 grams (approx.)
- Mounting Position: Any
- Marking: Type Number





DO-41						
Dim	Min	Max				
Α	25.40	_				
В	4.06	5.21				
С	0.71	0.864				
D	2.00	2.72				
All Dimensions in mm						

Maximum Ratings and Electrical Characteristics T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	1N4933	1N4934	1N4935	1N4936	1N4937	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	Vrrm Vrwm Vr	50	100	200	400	600	V
RMS Reverse Voltage	VR(RMS)	35	70	140	280	420	V
Average Rectified Output Current (Note 1) $@T_A = 55^{\circ}C$	lo	1.0				А	
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	IFSM			30			A
Forward Voltage $@I_F = 1.0A$	Vfm	1.2				V	
Peak Reverse Current $@T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_A = 100^{\circ}C$	RM	5.0 100					μA
Reverse Recovery Time (Note 2)	trr	200			nS		
Typical Junction Capacitance (Note 3)	Cj	15			pF		
Operating Temperature Range	Tj	-65 to +125			°C		
Storage Temperature Range	Тѕтс	-65 to +150			°C		

*Glass passivated forms are available upon request

- Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case
 - 2. Measured with IF = 0.5A, IR = 1.0A, IRR = 0.25A. See figure 5.
 - 3. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.



RATING AND CHARACTERISTIC CURVES 1N4933 THRU 1N4937

